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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/754,546	01/12/2004	Jae-Bon Koo	6161.0118.US	9275

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EXAMINER

NGUYEN, THANH NHAN P

ART UNIT	PAPER NUMBER
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2871

DATE MAILED: 11/01/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

10/754,546

Applicant(s)

KOO ET AL.

Examiner

(Nancy) Thanh-Nhan P. Nguyen

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 17 August 2005.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-15 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-4, 6, 8-15 is/are rejected.
- 7) ☒ Claim(s) 5 and 7 is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 16 June 2004 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
- 1) ☒ Certified copies of the priority documents have been received.
 - 2) ☐ Certified copies of the priority documents have been received in Application No. _____.
 - 3) ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- 1) ☐ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____

- 4) ☐ Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____
- 5) ☐ Notice of Informal Patent Application (PTO-152)
- 6) ☒ Other: Attachment provided by Examiner.

DETAILED ACTION

1. This communication is responsive to Amendment dated 8/17/2005.
2. Claims 1-15 are pending for the examination.
3. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.
4. The rejections are respectfully maintained and reproduced infra for applicants' convenience.

Claim Rejections - 35 USC § 102

Claims 10-15 are rejected under 35 U.S.C. 102(b) as being anticipated by Ohtani et al U.S. Patent No. 6,303,963.

Referring to claim 10, Ohtani et al discloses a flat panel display having a matrix-type array of sub-pixels, each of which comprises a driving thin film transistor (3503), a first electrode (3609) driven by the driving thin film transistor, and a second electrode (3613) driving a light emission unit (3505) together with the first electrode, [see fig. 18]; wherein the driving thin film transistor comprises semiconductor channels which are derived from a semiconductor layer, and heterogeneous straight lines are separated from each other on the semiconductor layer, and wherein each of the semiconductor channels comprises at least one of the heterogeneous straight lines, [see figs. 2D, or 6B-6E, or 7A-7D].

Referring to claim 11, inherently, the semiconductor channels comprise the same number of the heterogeneous straight lines.

Referring to claim 12, inherently, the semiconductor channels has a length equal to a value obtained by multiplying the width of a laser beam irradiated for crystallization of amorphous silicon into polycrystalline silicon by the percentage of the area of the semiconductor layer at which overlap of the laser beam does not occur.

Referring to claim 13, Ohtani et al discloses the heterogeneous straight lines are separated from each other by the same distance, [see fig. 7D].

Referring to claim 14, Ohtani et al discloses a flat panel display having a matrix-type array of sub-pixels, each of which comprises a driving thin film transistor (3503), a first electrode (3609) driven by the driving thin film transistor, and a second electrode (3613) driving a light emission unit (3505) together with the first electrode, [see fig. 18]; wherein the driving thin film transistor comprises semiconductor channels which are derived from a semiconductor layer, and heterogeneous straight lines are separated from each other on the semiconductor layer, and wherein of the semiconductor channels are positioned between the heterogenous straight lines, [see figs. 2D, or 6B-6E, or 7A-7D].

Referring to claim 15, Ohtani et al discloses the heterogeneous straight lines are separated from each other by the same distance, [see fig. 7D].

Claim Rejections - 35 USC § 103

Claims 1-4, 6, 8 & 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ohtani et al in view of Komiya et al U.S. Patent No. 6,456,013.

Referring to claim 1, Ohtani et al discloses a flat panel display having a matrix-type array of sub-pixels, each of which comprises a driving thin film transistor (3503), a

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first electrode (3609) driven by the driving thin film transistor, and a second electrode (3613) driving a light emission unit (3505) together with the first electrode, [see fig. 18]; wherein the driving thin film transistor comprises semiconductor channels which are derived from a semiconductor layer; and heterogeneous straight lines are separated from each other on the semiconductor layer, [see figs. 2D, or 6B-6E, or 7A-7D].

Ohtani et al lacks disclosure of an imaginary line connecting the semiconductor channels of one column is not parallel to the heterogeneous straight lines.

Komiya et al discloses an imaginary line connecting the semiconductor channels of one column is not parallel to the heterogeneous straight lines, [see fig. 3], for the benefit of suppressing the leak current in the switching thin film transistors (TFT) to maintain the potential of the gate electrode of the element driving TFT at a fixed level, thereby allowing the electroluminescence (EL) element to emit light at a desired luminance, [see col. 5, lines 4-7]. Therefore, at the time the invention was made, it would have been obvious to one ordinary skill in the art to have an imaginary line connecting the semiconductor channels of one column is not parallel to the heterogeneous straight lines for the benefit of suppressing the leak current in the switching thin film transistors (TFT) to maintain the potential of the gate electrode of the element driving TFT at a fixed level, thereby allowing the electroluminescence (EL) element to emit light at a desired luminance.

Referring to claim 8, Ohtani et al discloses the heterogeneous straight lines are separated from each other by the same distance, [see fig. 7D].

Referring to claims 2-4, 6 & 9, Ohtani et al lacks disclosure of the imaginary line connecting the semiconductor channels of one column is in a non-straight line; the imaginary line connecting the semiconductor channels of one column is a zig-zag line, wherein the zig-zag line has a regular zig-zag pattern; wherein the zig-zag line has a two-step zig-zag pattern; wherein the heterogeneous straight lines are separated from each other by the same distance and the width of the zig-zag line is larger than the distance between adjacent two of the heterogeneous straight lines.

However, all the listed features in claims 2-4, 6 & 9 are described in Komiya's disclosure, particularly in fig. 3, as being for the benefit that discussed in claim 1 above.

Allowable Subject Matter

Claims 5 & 7 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: The claim is allowable over the prior art of record because none of the references, either alone or in combination, discloses or renders obvious the flat panel display comprising the imaginary line connecting the semiconductor channels of one column is a zig-zag line, wherein the zig-zag line has a non-uniform zig-zag pattern, or wherein the zig-zag line has three-step zig-zag pattern.

Response to Arguments

Applicant's arguments filed 8/17/2005 have been fully considered but they are not persuasive.

Applicants' argument: In the Remarks, page 7, "The Examiner claims that "heterogeneous straight lines" are shown in Figs. 2D, 6A-6E, and 7A-7D of Ohtani; however, Applicants assert that it is impossible to determine the existence of the heterogeneous lines based on these figures... The figures cited by Examiner clearly do not show the heterogeneous straight lines and the arrangement of the semiconductor channels with respect to the heterogeneous straight lines."

Examiner's response: Conventionally, when forming channels (for thin film transistors) from the amorphous semiconductor layer, the gate electrode was usually used as a mask. Therefore, after laser crystallization, the amorphous semiconductor layer became polycrystalline semiconductor layer with regions of crystallized and region of less crystallized. The heterogeneous straight lines were at the boundary of the regions of crystallized and region of less crystallized, [see figures from attachment provided by Examiner in this Office Action]. The figures that Examiner cited from Ohtani reference (from previous Office Action) were the evidence of forming the channel (for thin film transistor) from the amorphous semiconductor layer, and the heterogeneous straight lines inherently formed after laser crystallization.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not

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mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Contact Information

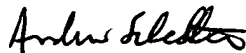
Any inquiry concerning this communication or earlier communications from the examiner should be directed to (Nancy) Thanh-Nhan P. Nguyen whose telephone number is 571-272-1673. The examiner can normally be reached on M-F/9-5:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert Kim can be reached on 571-272-2293. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

(Nancy) Thanh-Nhan P. Nguyen
Examiner
Art Unit 2871
-- October 20, 2005 --

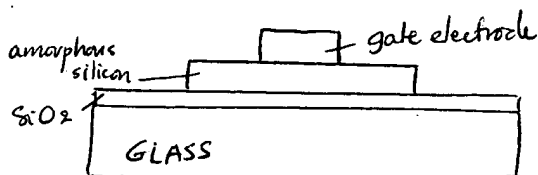
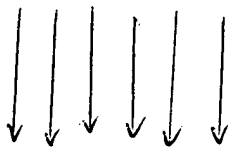
TN


ANDREW SCHECHTER
PRIMARY EXAMINER

Attachment for 10/754,546 <Final Rejection - Paper No. 20051019>

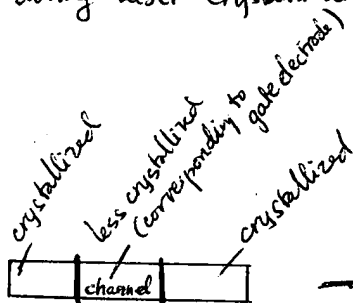
①

laser crystallization



- Front View of Amorphous Semiconductor during Laser Crystallization

②



→ the lines at the boundary of the regions of crystallized & region of less crystallized are heterogenous straight lines.

- Top View of Polycrystalline Semiconductor after Laser Crystallization